



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

July 16, 2026

IGI Report Number

LG801694444

Description

LABORATORY GROWN DIAMOND

Shape and Cutting Style

MARQUISE BRILLIANT

Measurements

10.45 X 5.44 X 3.53 MM

GRADING RESULTS

Carat Weight

1.20 CARAT

Color Grade

D

Clarity Grade

FLAWLESS

ADDITIONAL GRADING INFORMATION

Polish

EXCELLENT

Symmetry

EXCELLENT

Fluorescence

NONE

Inscription(s)

 LG801694444

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.
Type II

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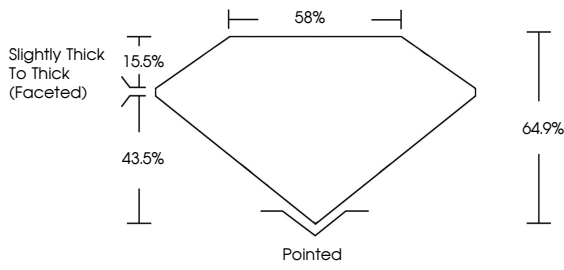
NONE

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PROPORTIONS



Slightly Thick To Thick (Faceted)

58%

15.5%

43.5%

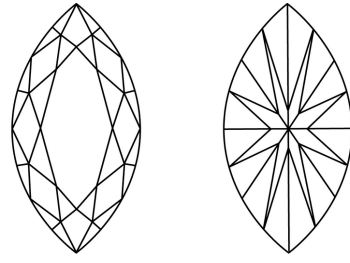
64.9%

Pointed



Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL IF VVS¹⁻² VS¹⁻² SI¹⁻² I¹⁻³

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included



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MARQUISE BRILLIANT

10.45 X 5.44 X 3.53 MM

1.20 CARAT

D

FLAWLESS

D

64.9%

85%

Slightly Thick To Thick (Faceted)

Pointed

EXCELLENT

EXCELLENT

NONE

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